TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

2SC3669

Power Amplifier Applications
Power Switching Applications

- Low collector saturation voltage: $V_{CE (sat)} = 0.5 \text{ V (max) (IC} = 1 \text{ A)}$
- High-speed switching: $t_{stg} = 1.0 \mu s$ (typ.)
- Complementary to 2SA1429

Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|-----------------------------|------------------|------------|------|
| Collector-base voltage | V_{CBO} | 80 | V |
| Collector-emitter voltage | V_{CEO} | 80 | V |
| Emitter-base voltage | V _{EBO} | 5 | V |
| Collector current | I _C | 2 | Α |
| Base current | ΙΒ | 1 | Α |
| Collector power dissipation | PC | 1000 | mW |
| Junction temperature | Tj | 150 | °C |
| Storage temperature range | T _{stg} | -55 to 150 | °C |

7.1MAX 3.8 2.7MAX 3.8 3.2 0.55 - 0.05 0.85 40.15 0.45 - 0.05 1 2 3 1.025 ± 0.05 1. BASE 2. COLLECTOR 3. EMITTER JEDEC JEITA TOSHIBA 2-7D101A

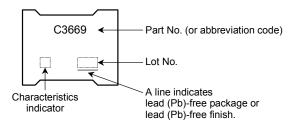
Weight: 0.2 g (typ.)

Electrical Characteristics (Ta = 25°C)

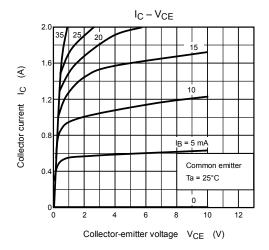
| Chara | acteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------------|--------------------|----------------------------|--|-----|------|-----|------|
| Collector cut-off of | current | I _{CBO} | V _{CB} = 80 V, I _E = 0 | _ | _ | 1.0 | μA |
| Emitter cut-off cu | rrent | I _{EBO} | V _{EB} = 5 V, I _C = 0 | _ | _ | 1.0 | μA |
| Collector-emitter | breakdown voltage | V (BR) CEO | I _C = 10 mA, I _B = 0 | 80 | _ | - | V |
| DC current gain | | h _{FE (1)} (Note) | V _{CE} = 2 V, I _C = 0.5 A | 70 | _ | 240 | |
| | | h _{FE (2)} | V _{CE} = 2 V, I _C = 1.5 A | 40 | _ | _ | |
| Collector-emitter | saturation voltage | V _{CE (sat)} | I _C = 1 A, I _B = 0.05 A | _ | 0.15 | 0.5 | V |
| Base-emitter satu | uration voltage | V _{BE (sat)} | I _C = 1 A, I _B = 0.05 A | _ | 0.9 | 1.2 | V |
| Transition freque | ncy | f _T | V _{CE} = 2 V, I _C = 0.5 A | _ | 100 | _ | MHz |
| Collector output capacitance | | C _{ob} | V _{CB} = 10 V, I _E = 0, f = 1 MHz | _ | 30 | _ | pF |
| Switching time | Turn-on time | t _{on} | 20 μs Input IB1 Output $\stackrel{\square}{\longrightarrow}$ | _ | 0.2 | _ | |
| | Storage time | t _{stg} | | _ | 1.0 | _ | μs |
| | Fall time | t _f | | _ | 0.2 | _ | |

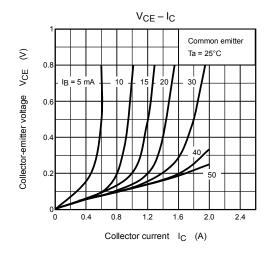
Note: $h_{FE\ (1)}$ classification O: 70 to 140, Y: 120 to 240

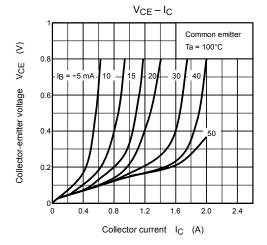
Marking

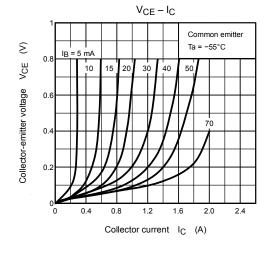


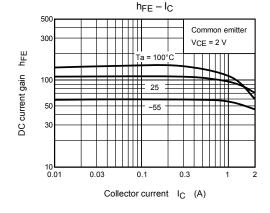
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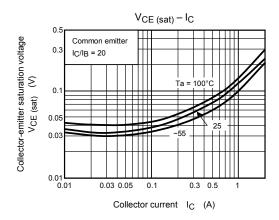


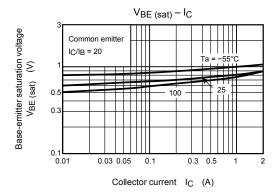


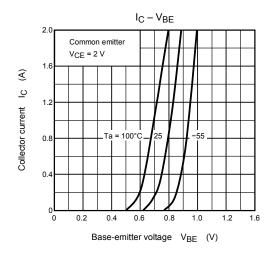












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